Ordering number : ENA2004A

SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

N-Channel Silicon MOSFET

MCH6448 — Low-Voltage Driver Switching Device Applications

Features

- ON-resistance $R_{DS}(on)1$=17mΩ (typ.)
- 1.2V drive
- Halogen free compliance
- Protection diode in

Specifications

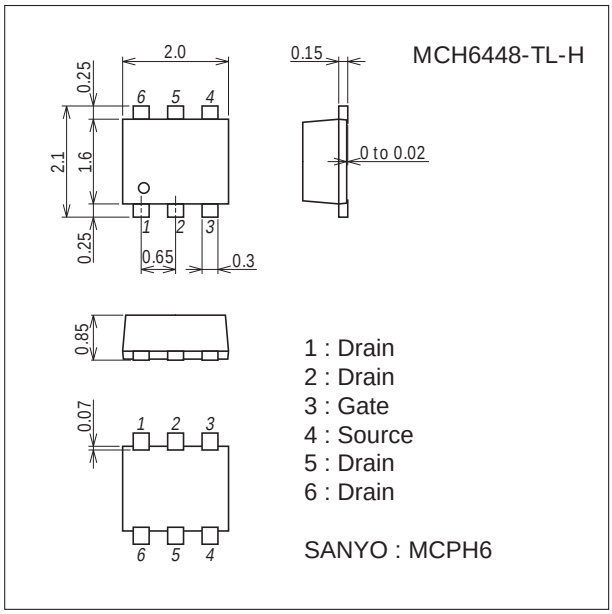
Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V_{DSS}		20	V
Gate-to-Source Voltage	V_{GSS}		±9	V
Drain Current (DC)	I_D		8	A
Drain Current (Pulse)	I_{DP}	PW≤10μs, duty cycle≤1%	32	A
Allowable Power Dissipation	P_D	When mounted on ceramic substrate (1200mm²×0.8mm)	1.5	W
Channel Temperature	Tch		150	℃
Storage Temperature	Tstg		−55 to +150	℃

Package Dimensions

unit : mm (typ)

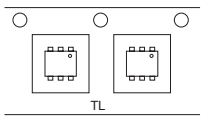
7022A-009



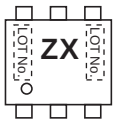
Product & Package Information

- Package : MCPH6
- JEITA, JEDEC : SC-88, SC-70-6, SOT-363
- Minimum Packing Quantity : 3,000 pcs./reel

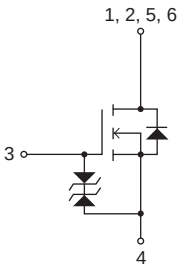
Packing Type : TL



Marking



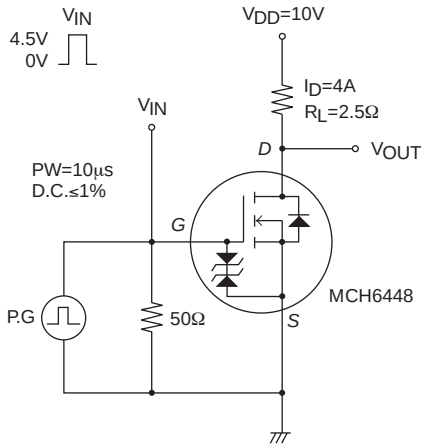
Electrical Connection



Electrical Characteristics at Ta=25°C

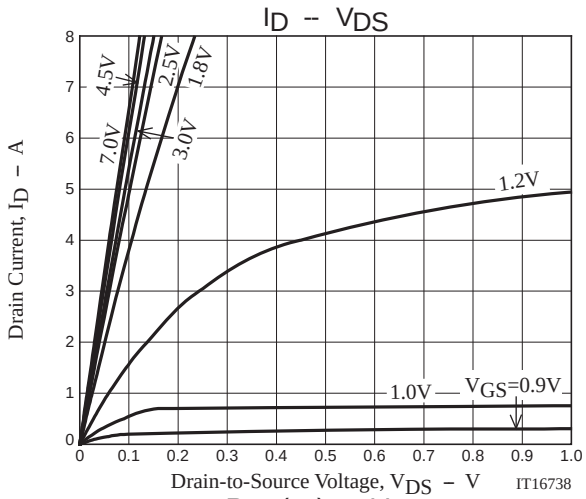
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	I_D=1mA, V_{GS}=0V	20			V
Zero-Gate Voltage Drain Current	I_{DSS}	V_{DS}=20V, V_{GS}=0V			1	μA
Gate-to-Source Leakage Current	I_{GSS}	V_{GS}=±7.2V, V_{DS}=0V			±10	μA
Cutoff Voltage	V_{GS}(off)	V_{DS}=10V, I_D=1mA	0.3		1.0	V
Forward Transfer Admittance	| yfs |	V_{DS}=10V, I_D=4A		7.7		S
Static Drain-to-Source On-State Resistance	R_{DS}(on)1	I_D=4A, V_{GS}=4.5V		17	22	mΩ
	R_{DS}(on)2	I_D=2A, V_{GS}=2.5V		20	28	mΩ
	R_{DS}(on)3	I_D=1A, V_{GS}=1.8V		26	39	mΩ
	R_{DS}(on)4	I_D=0.5A, V_{GS}=1.2V		62	124	mΩ
Input Capacitance	Ciss	V_{DS}=10V, f=1MHz		705		pF
Output Capacitance	Coss			150		pF
Reverse Transfer Capacitance	Crss			125		pF
Turn-ON Delay Time	t_d(on)	See specified Test Circuit		6		ns
Rise Time	t_r			47		ns
Turn-OFF Delay Time	t_d(off)			103		ns
Fall Time	t_f			81		ns
Total Gate Charge	Qg	V_{DS}=10V, V_{GS}=4.5V, I_D=8A		11.2		nC
Gate-to-Source Charge	Qgs			1.3		nC
Gate-to-Drain “Miller” Charge	Qgd			2.8		nC
Diode Forward Voltage	V_{SD}	I_S=8A, V_{GS}=0V		0.8	1.2	V

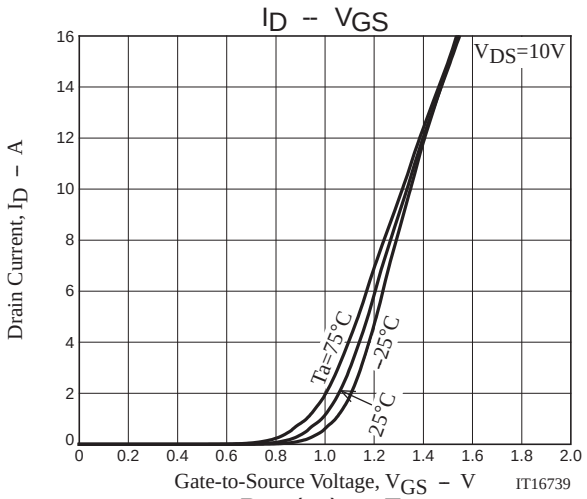
Switching Time Test Circuit

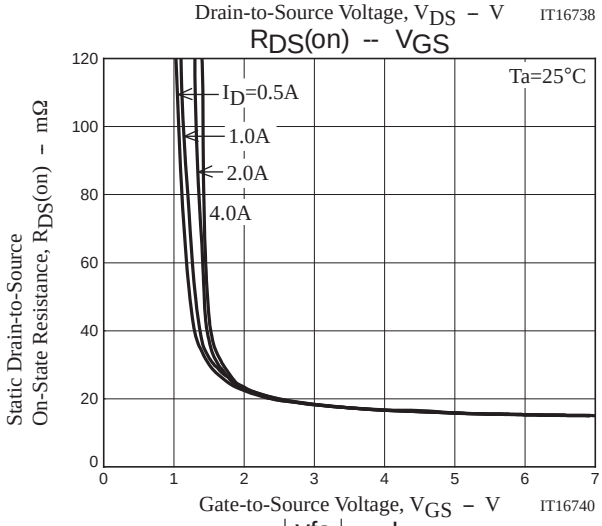


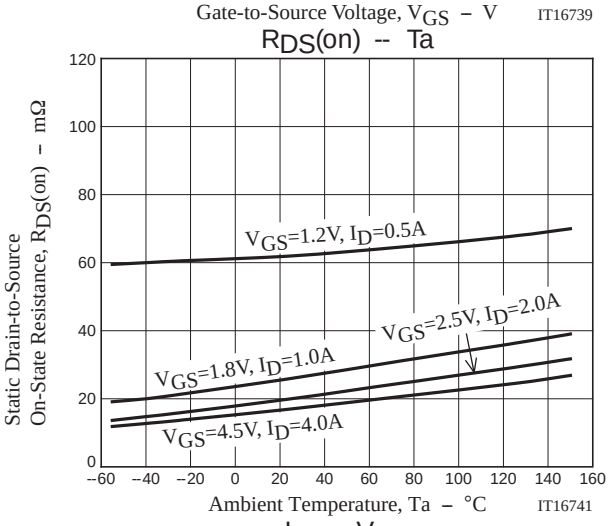
Ordering Information

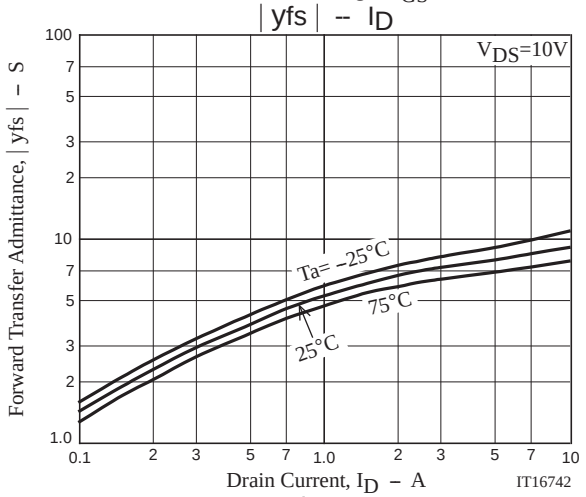
Device	Package	Shipping	memo
MCH6448-TL-H	MCPH6	3,000pcs./reel	Pb Free and Halogen Free

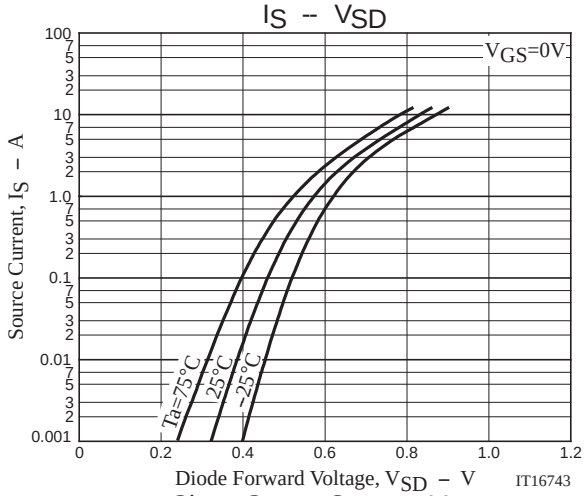

ID -- VDS
Drain Current, ID – A
Drain-to-Source Voltage, VDS – V
IT16738
4.5V
2.5V
1.8V
7.0V
3.0V
1.2V
1.0V
VGS=0.9V

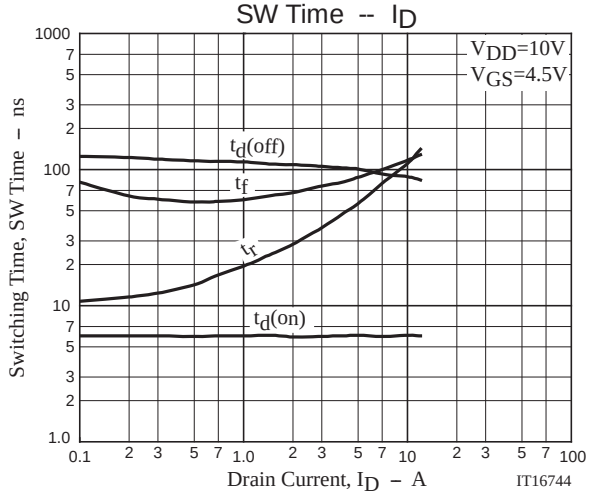

ID -- VGS
Drain Current, ID – A
Gate-to-Source Voltage, VGS – V
IT16739
VDS=10V
Ta=75°C
–25°C
25°C

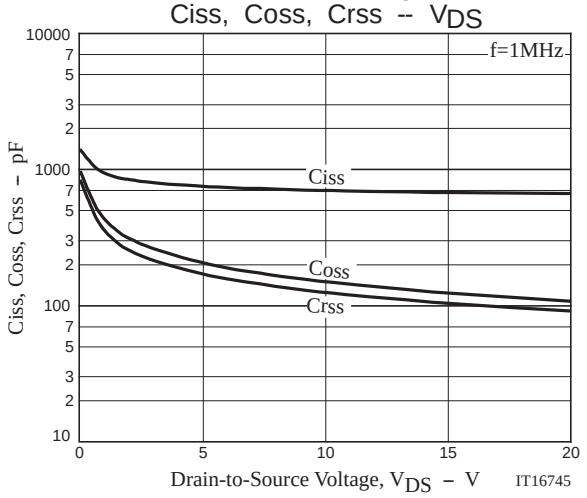

RDS(on) -- VGS
Static Drain-to-Source On-State Resistance, RDS(on) – mΩ
Gate-to-Source Voltage, VGS – V
IT16740
Ta=25°C
ID=0.5A
1.0A
2.0A
4.0A

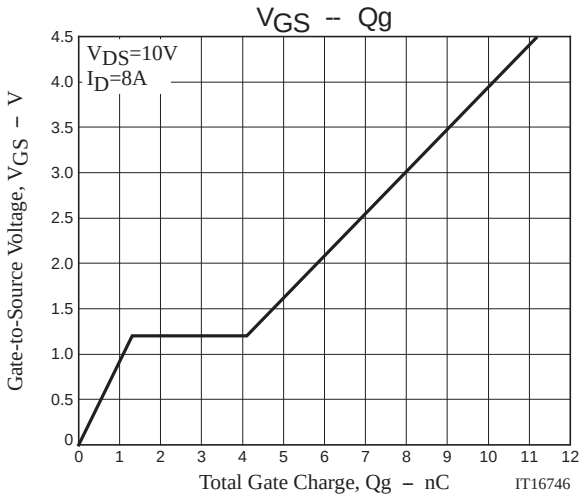

RDS(on) -- Ta
Static Drain-to-Source On-State Resistance, RDS(on) – mΩ
Ambient Temperature, Ta – °C
IT16741
VGS=1.2V, ID=0.5A
VGS=2.5V, ID=2.0A
VGS=1.8V, ID=1.0A
VGS=4.5V, ID=4.0A

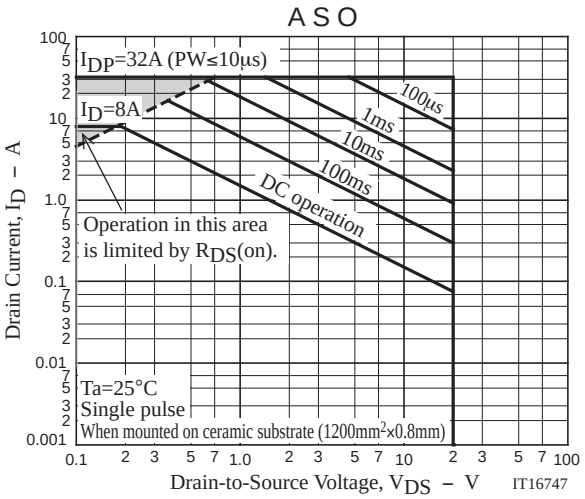

| yfs | -- ID
Forward Transfer Admittance, | yfs | – S
Drain Current, ID – A
IT16742
VDS=10V
Ta= –25°C
75°C
25°C

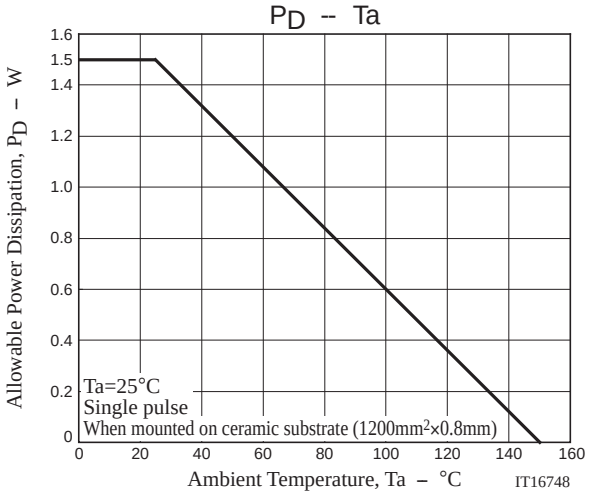

IS -- VSD
Source Current, IS – A
Diode Forward Voltage, VSD – V
IT16743
VGS=0V
Ta=75°C
25°C
–25°C


SW Time -- ID
Switching Time, SW Time – ns
Drain Current, ID – A
IT16744
VDD=10V
VGS=4.5V
td(off)
tf
tr
td(on)


Ciss, Coss, Crss -- VDS
Ciss, Coss, Crss – pF
Drain-to-Source Voltage, VDS – V
IT16745
f=1MHz
Ciss
Coss
Crss


VGS – Qg
VDS=10V
ID=8A
Gate-to-Source Voltage, VGS – V
Total Gate Charge, Qg – nC
IT16746


A S O
IDP=32A (PW≤10μs)
ID=8A
100μs
1ms
10ms
100ms
DC operation
Operation in this area
is limited by RDS(on).
Ta=25°C
Single pulse
When mounted on ceramic substrate (1200mm2×0.8mm)
Drain Current, ID – A
Drain-to-Source Voltage, VDS – V
IT16747


PD -- Ta
Ta=25°C
Single pulse
When mounted on ceramic substrate (1200mm2×0.8mm)
Allowable Power Dissipation, PD – W
Ambient Temperature, Ta – °C
IT16748

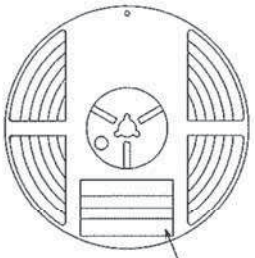
Taping Specification

MCH6448-TL-H

1. Packing Format

Package Name	Carrier Tape Type	Maximun Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
MCPH6	MCP4	3,000	15,000	90,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

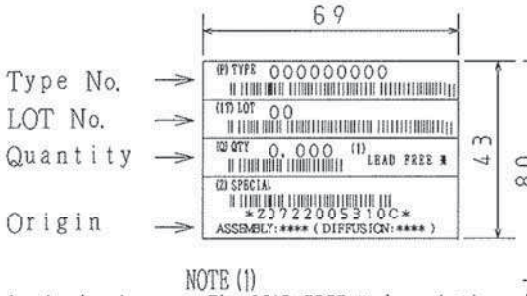
Packing method



Reel label

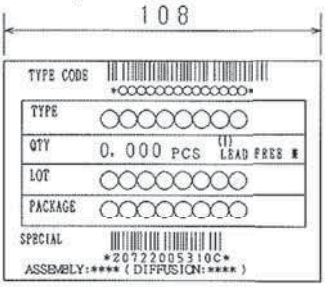
Reel label, Inner box label

(unit:mm)



Outer box label

It is a label at the time of factory shipments. The form of a label may change in physical distribution process.

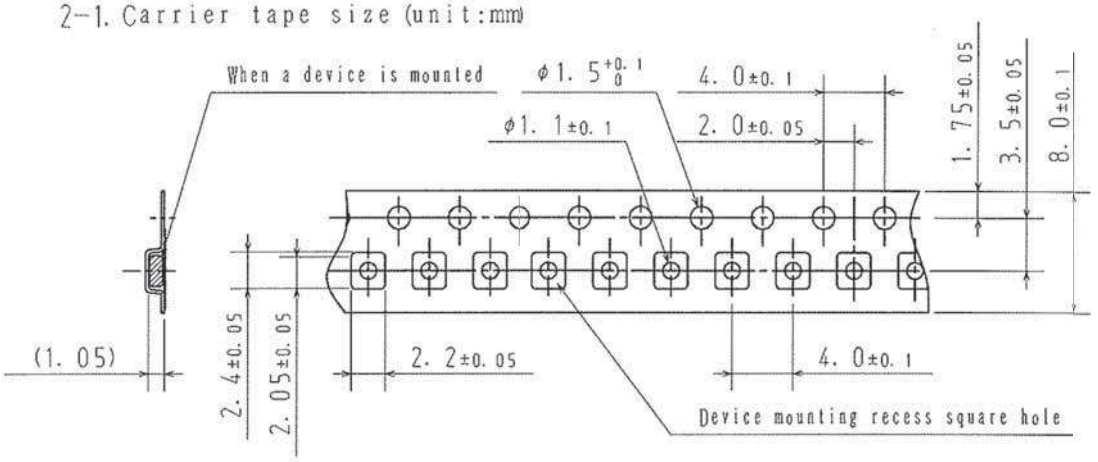


NOTE (1)
The LEAD FREE ※ description shows that the surface treatment of the terminal is lead free.

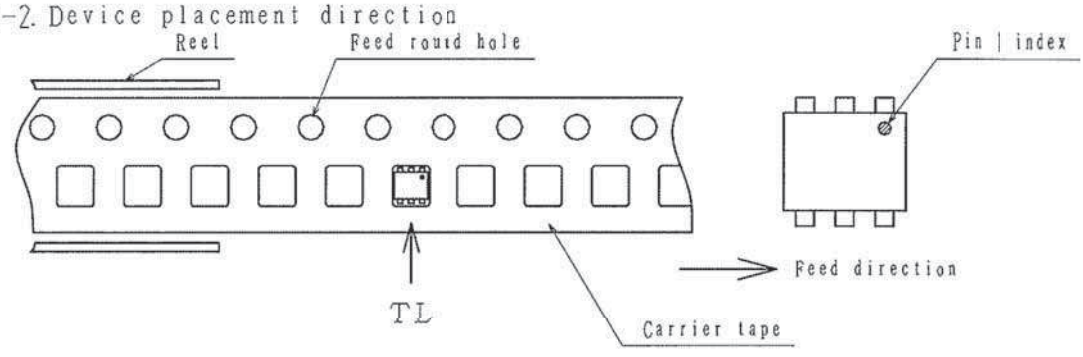
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)



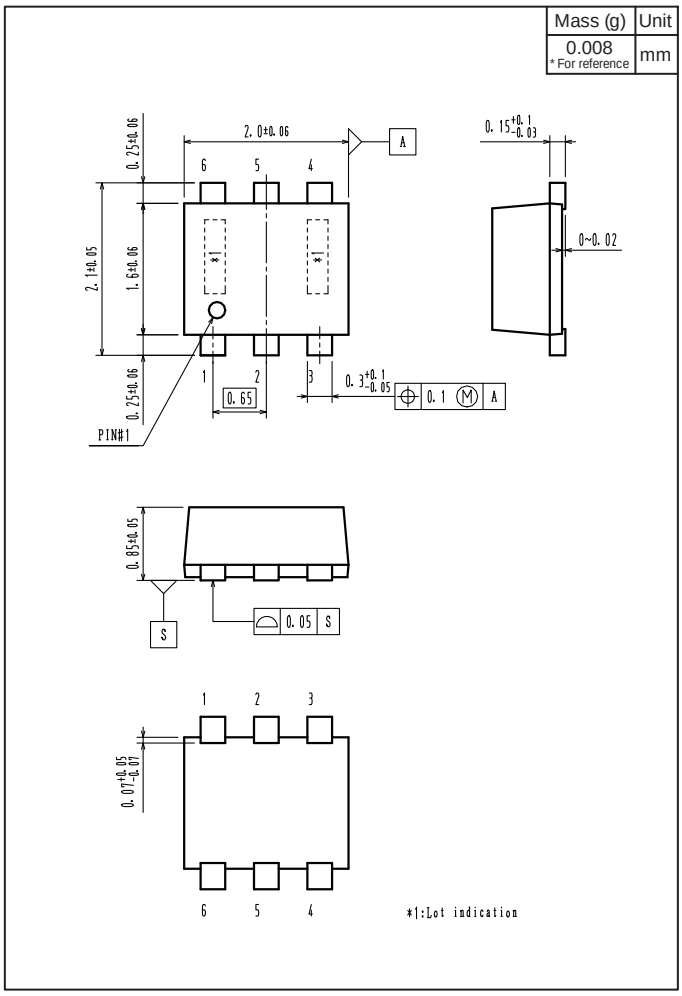
2-2. Device placement direction



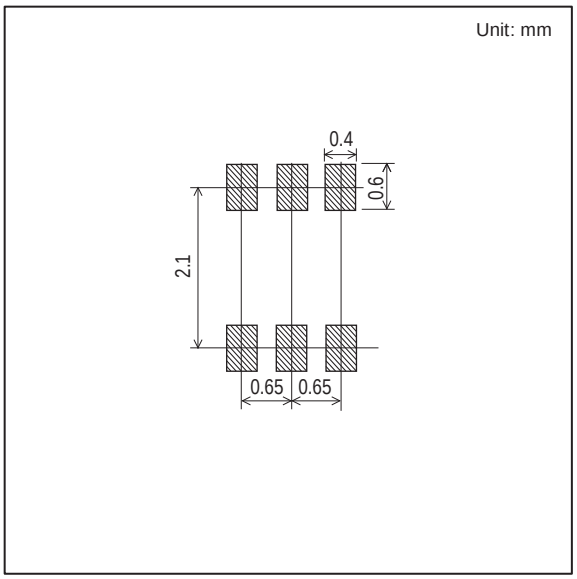
Those with pin 1 index on the feed hole side·····TL

Outline Drawing

MCH6448-TL-H



Land Pattern Example



Note on usage : Since the MCH6448 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

This catalog provides information as of June, 2012. Specifications and information herein are subject to change without notice.